

P-Channel Enhancement Mode MOSFET

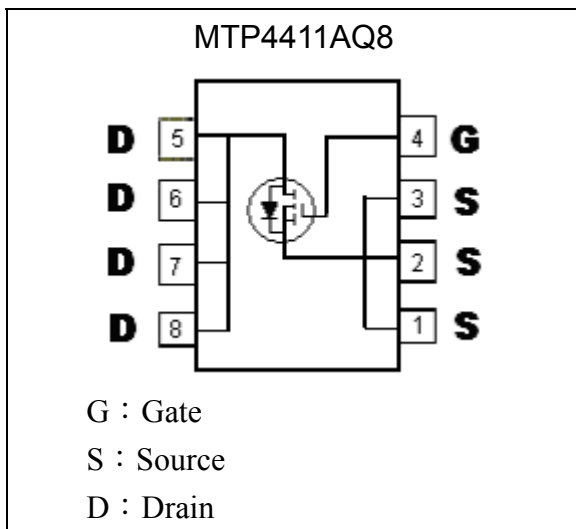
MTP4411AQ8

BV _{DSS}	-30V
I _D @V _{GS} =-10V, T _A =25°C	-5.3A
R _{DS(on)} @V _{GS} =-10V, I _D =-5.3A	30mΩ (typ)
R _{DS(on)} @V _{GS} =-4.5V, I _D =-4.2A	43mΩ (typ)

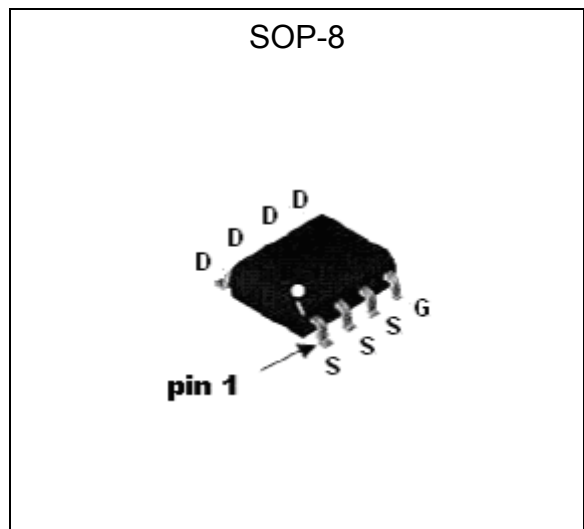
Features

- Simple drive requirement
- Low on-resistance
- Fast switching speed
- Pb-free lead plating and halogen-free package

Equivalent Circuit

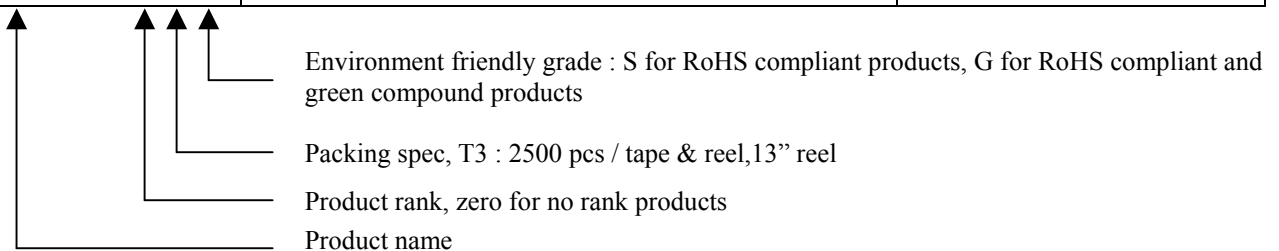


Outline



Ordering Information

Device	Package	Shipping
MTP4411AQ8-0-T3-G	SOP-8 (Pb-free lead plating and halogen-free package)	2500 pcs/ Tape & Reel





Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	-30	V
Gate-Source Voltage	V _{GS}	±25	
Continuous Drain Current @ V _{GS} =-10V, T _A =25°C (Note 1)	I _D	-5.3	A
Pulsed Drain Current (Note 2)	I _{DM}	-24	
Total Power Dissipation (Note 1)	P _d	2.5	W
Linear Derating Factor		0.02	W / °C
Operating Junction Temperature	T _j	-55~+150	°C
Storage Temperature	T _{stg}	-55~+150	

Note : 1.Surface mounted on FR-4 board, t≤10sec.
 2.Pulse width ≤300μs, Duty Cycle≤2%

Thermal Data

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-case, max	R _{θJC}	25	°C/W
Thermal Resistance, Junction-to-ambient, max	R _{θJA}	50 (Note)	

Note : Surface mounted on 1 in² copper pad of FR-4 board, pulse width≤10s.

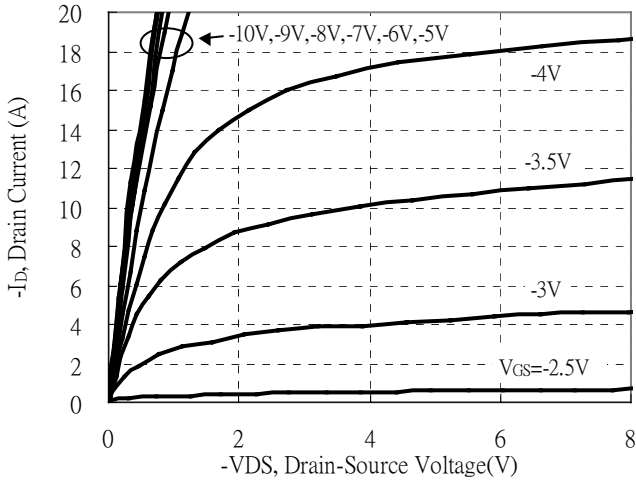
Electrical Characteristics (Tj=25°C, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV _{DSS}	-30	-	-	V	V _{GS} =0V, I _D =-250μA
V _{GS(th)}	-1	-1.5	-2.5	V	V _{DS} =V _{GS} , I _D =-250μA
I _{GSS}	-	-	±100	nA	V _{GS} =±25V, V _{DS} =0V
I _{DSS}	-	-	-1	μA	V _{DS} =-30V, V _{GS} =0V
*R _{DSON}	-	30	40	mΩ	I _D =-5.3A, V _{GS} =-10V
	-	43	60		I _D =-4.2A, V _{GS} =-4.5V
*G _{FS}	-	8	-	S	V _{DS} =-5V, I _D =-5.3A
Dynamic					
C _{iSS}	-	630	-	pF	V _{DS} =-15V, V _{GS} =0V, f=1MHz
C _{oSS}	-	76	-		
C _{rSS}	-	64	-		
*t _{d(ON)}	-	6	-	ns	V _{DD} =-15V, I _D =-1A, V _{GS} =-10V, R _G =6Ω
*t _r	-	17.4	-		
*t _{d(OFF)}	-	63.6	-		
*t _f	-	33.8	-		
*Q _g	-	14.2	-	nC	V _{DS} =-15V, V _{GS} =-10V, I _D =-5.3A
*Q _{gs}	-	2.1	-		
*Q _{gd}	-	2.8	-		
Source Drain Diode					
*V _{SD}	-	-0.79	-1.2	V	V _{GS} =0V, I _s =-1.7A

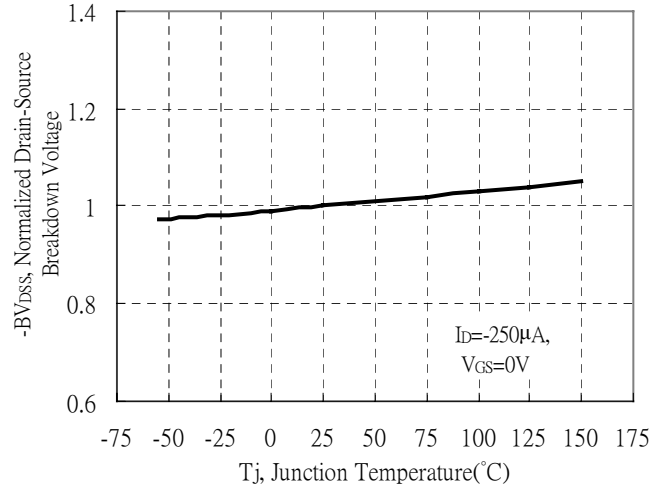
*Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

Typical Characteristics

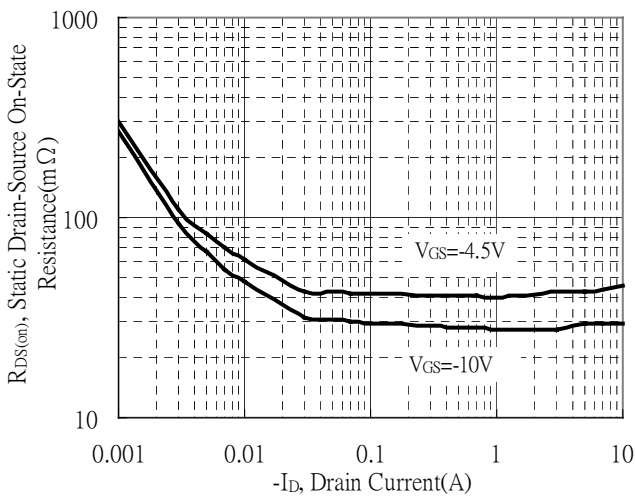
Typical Output Characteristics



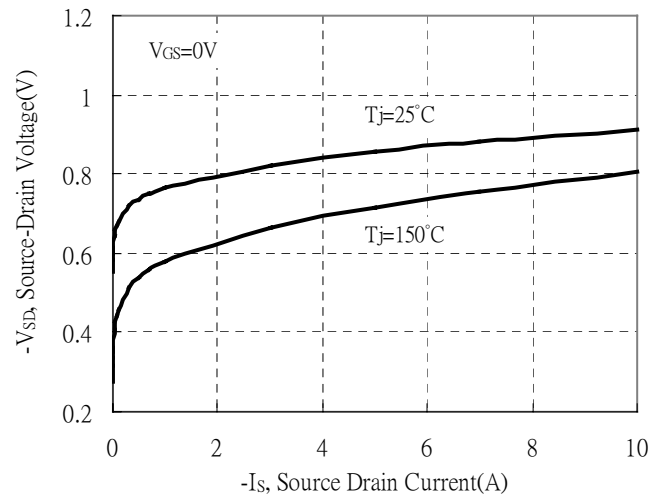
Breakdown Voltage vs Ambient Temperature



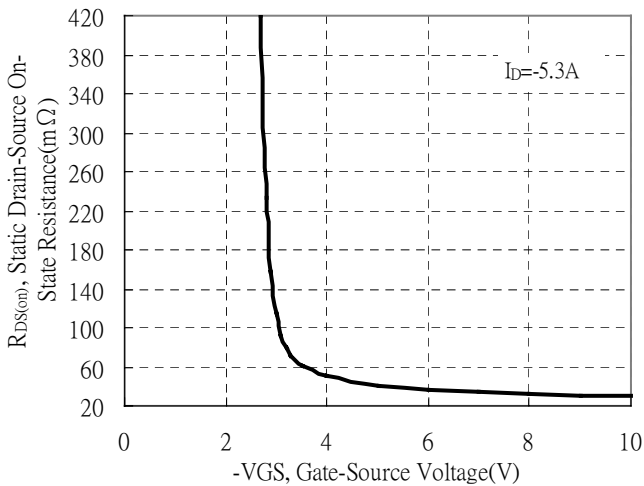
Static Drain-Source On-State resistance vs Drain Current



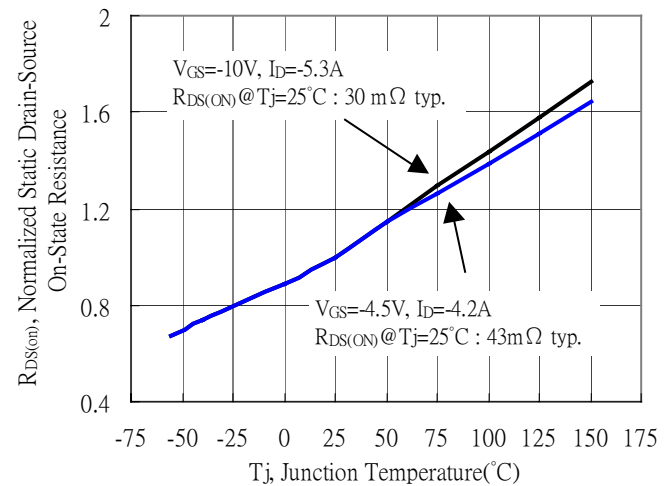
Source Drain Current vs Source-Drain Voltage



Static Drain-Source On-State Resistance vs Gate-Source Voltage

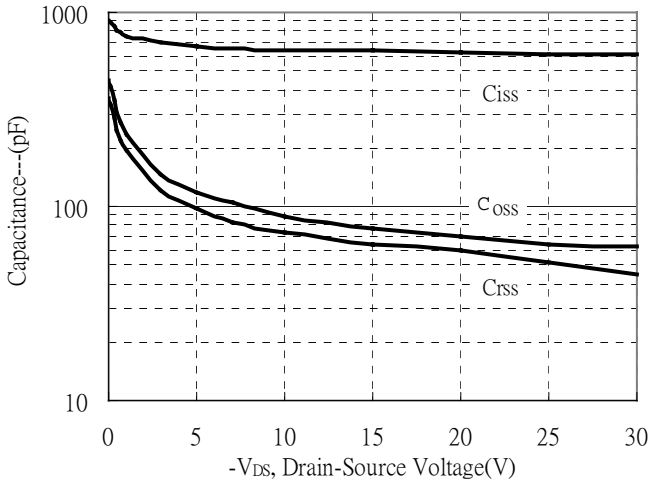


Drain-Source On-State Resistance vs Junction Temperature

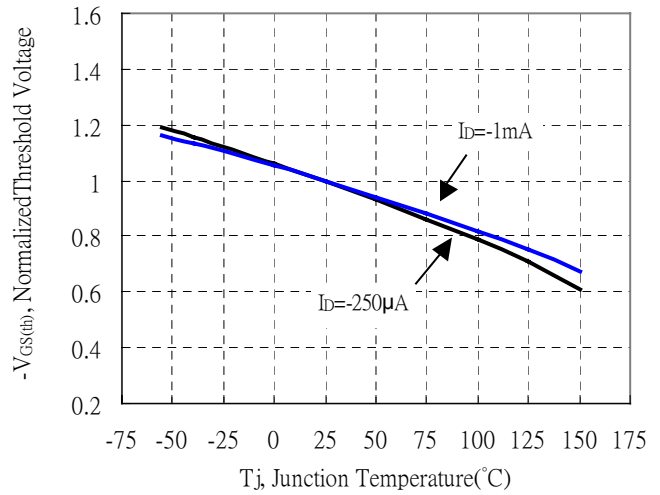


Typical Characteristics(Cont.)

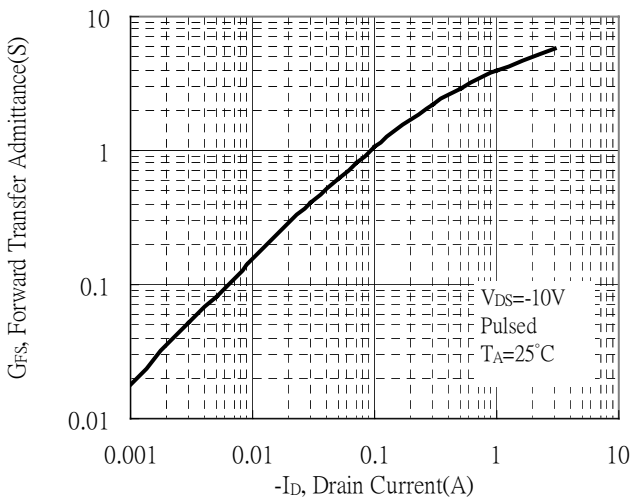
Capacitance vs Drain-to-Source Voltage



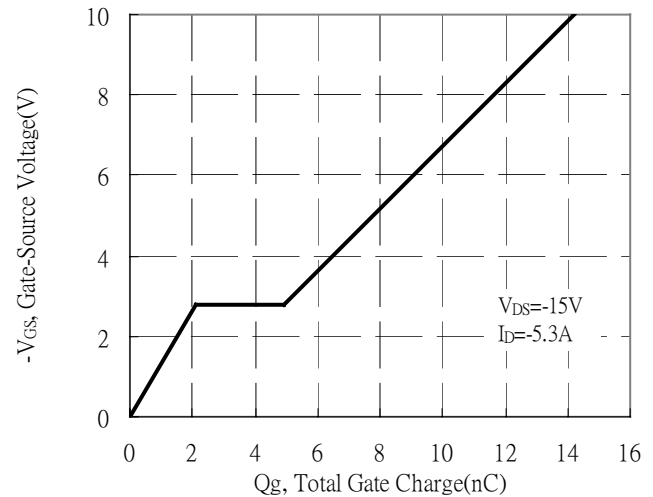
Threshold Voltage vs Junction Temperature



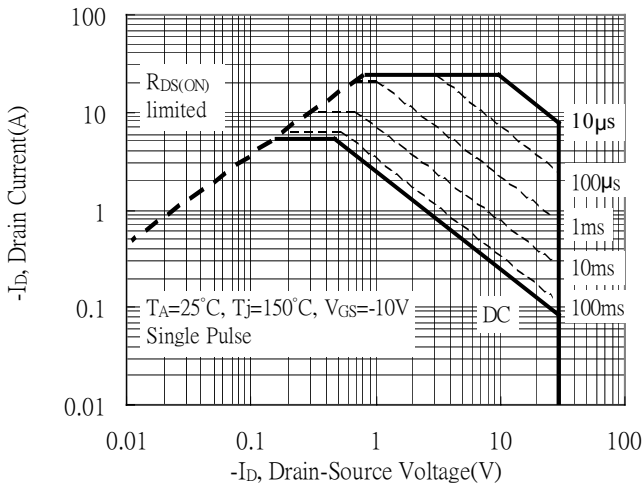
Forward Transfer Admittance vs Drain Current



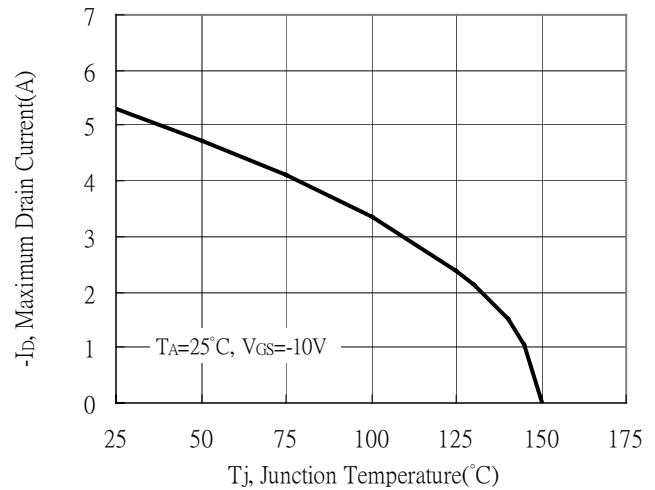
Gate Charge Characteristics



Maximum Safe Operating Area

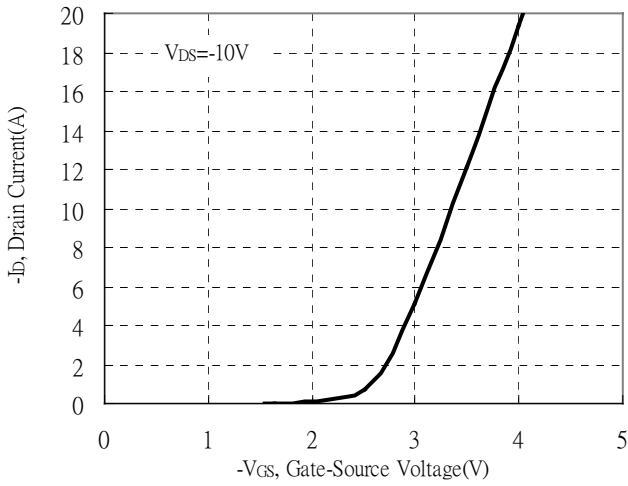


Maximum Drain Current vs Junction Temperature

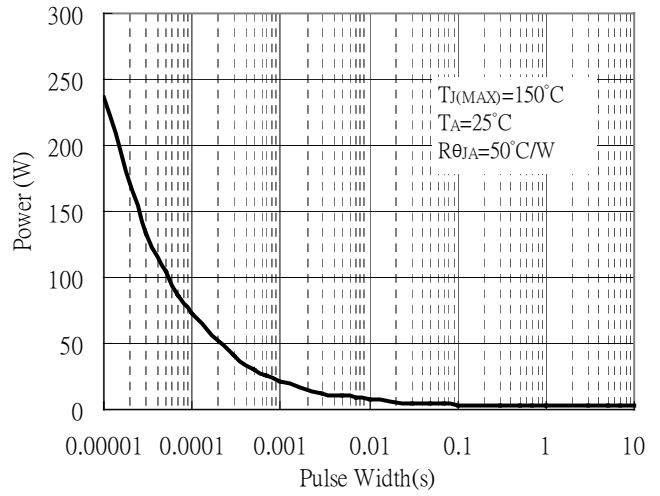


Typical Characteristics(Cont.)

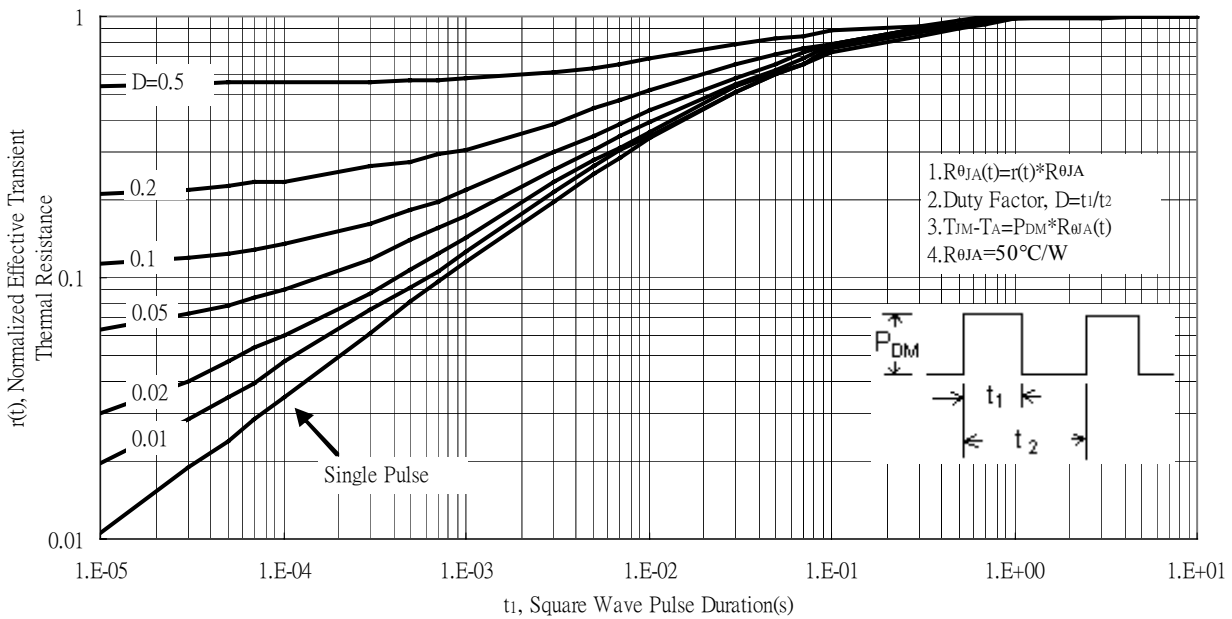
Typical Transfer Characteristics



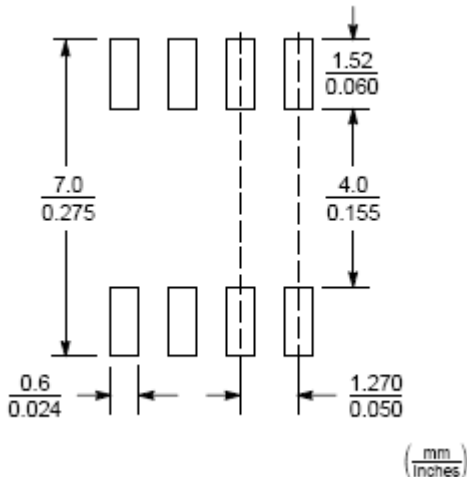
Single Pulse Power Rating, Junction to Ambient



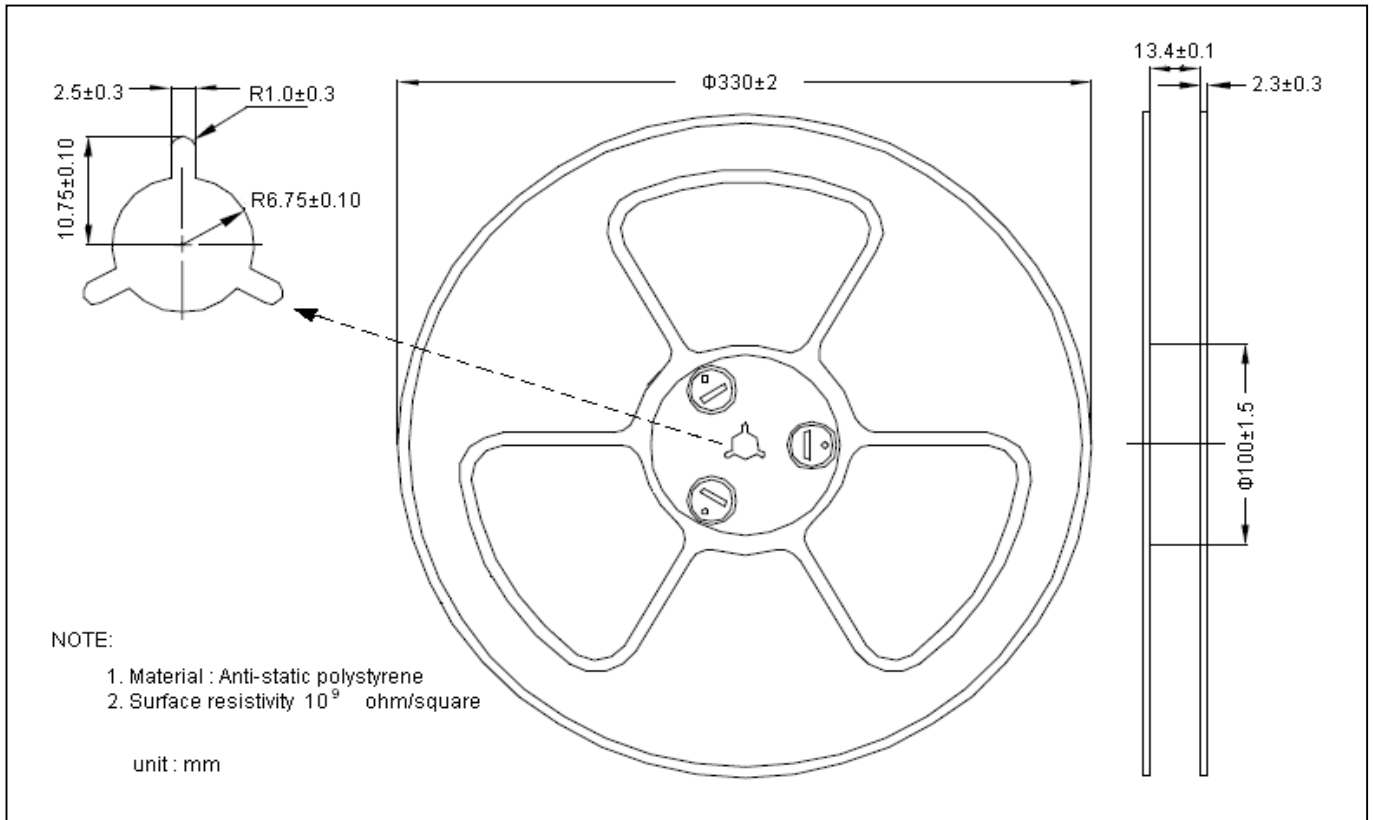
Transient Thermal Response Curves



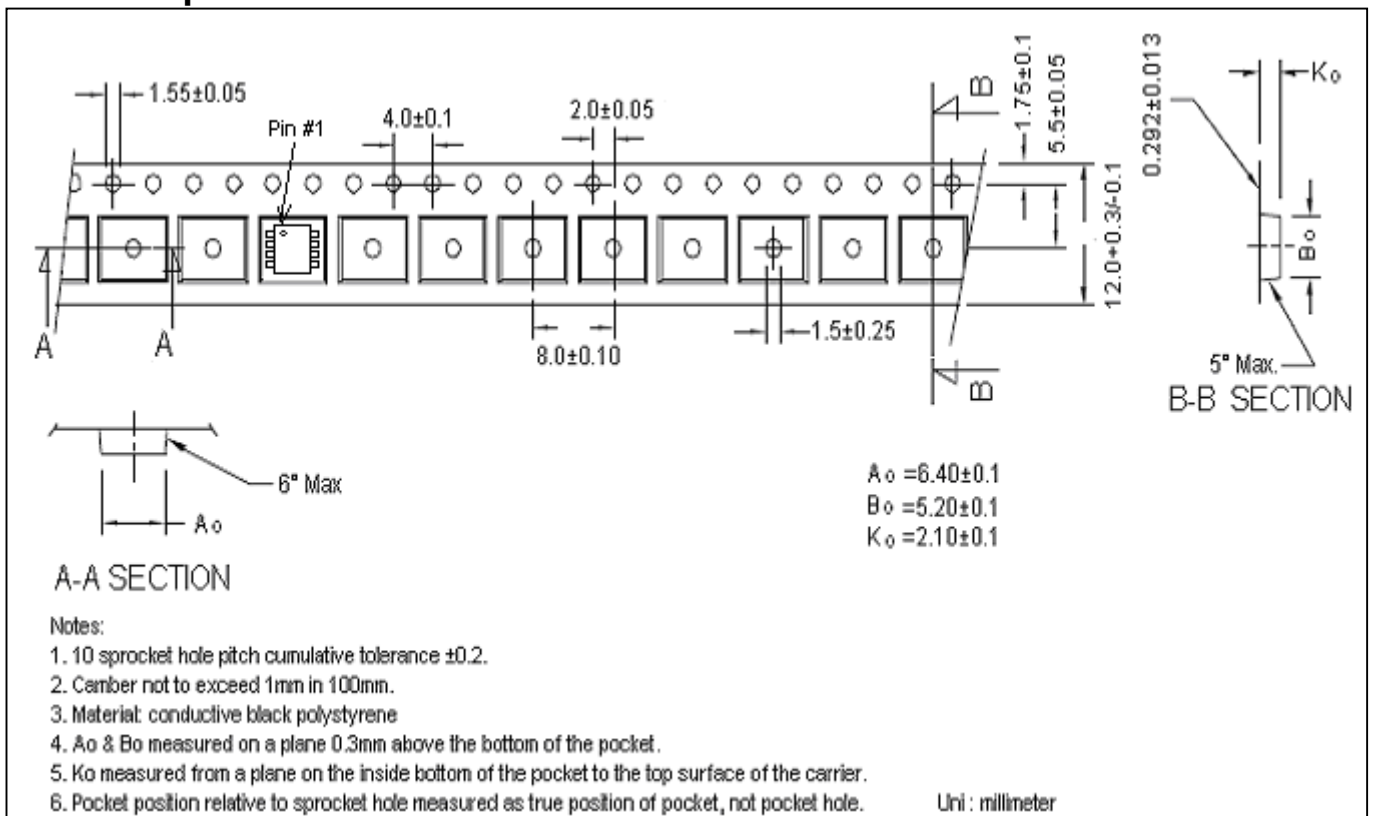
Recommended Soldering Footprint



Reel Dimension



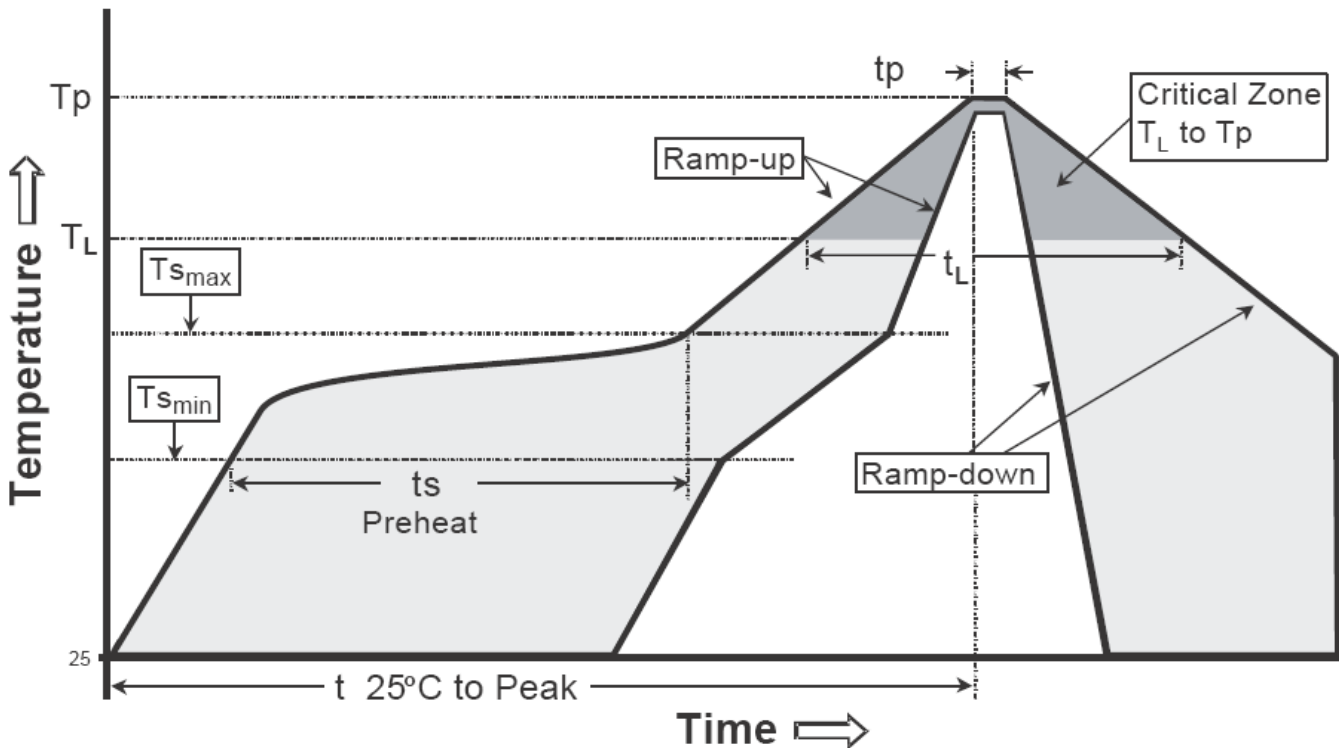
Carrier Tape Dimension



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

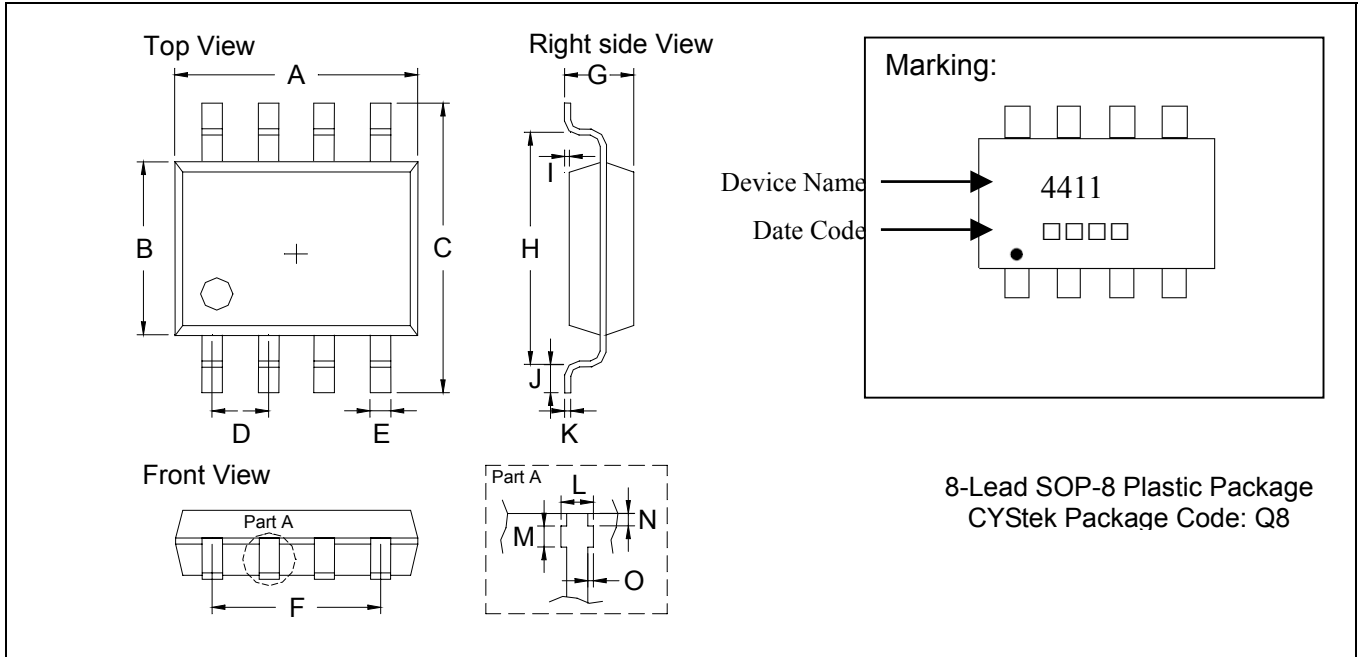
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(Ts min)	100°C	150°C
-Temperature Max(Ts max)	150°C	200°C
-Time(ts min to ts max)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (TL)	183°C	217°C
- Time (tL)	60-150 seconds	60-150 seconds
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOP-8 Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1890	0.2007	4.80	5.10	I	0.0098	REF	0.25	REF
B	0.1496	0.1654	3.80	4.20	J	0.0118	0.0354	0.30	0.90
C	0.2283	0.2441	5.80	6.20	K	0.0074	0.0098	0.19	0.25
D	0.0480	0.0519	1.22	1.32	L	0.0145	0.0204	0.37	0.52
E	0.0138	0.0193	0.35	0.49	M	0.0118	0.0197	0.30	0.50
F	0.1472	0.1527	3.74	3.88	N	0.0031	0.0051	0.08	0.13
G	0.0531	0.0689	1.35	1.75	O	0.0000	0.0059	0.00	0.15
H	0.1889	0.2007	4.80	5.10					

- Notes: 1. Controlling dimension: millimeters.
 2. Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3. If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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